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IEEE STD	IEEE Standard					
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			A V	.95-GHz InP HEMT MMIC amplifier with 427-mW power outp then, Y.C.; Ingram, D.L.; Lai, R.; Barsky, M.; Grunbacher, R.; Bi Incrowave and Guided Wave Letters. IEEE [see also IEEE Micro olume 8. Issue 11. Nov. 1988 Page(s) 399 - 401 lightal Object Litertifier 10.1109/75.738259	ock, T.; Yen, H.C.; Streit, D.C.;	
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			1	new empirical I-V model for HEMT devices chen, Y.C.; Ingram, D.L.; Yen, H.C.; Lai, R.; Streit, D.C.; decoveree and Guided Wave Letters. IEEE [see also IEEE Micro fotume 8, Issue 10, Oct. 1998 Page(s),342 - 344 Agital Object Identifier 10.11097/5.735415	ywave and Wireless Components L	
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		п	5. /	A low phase-error 44-GHz HEMT attenuator		
		П		Sjogren, L.; Ingram, D.; Biedenbender, M.; Lai, R.; Allen, B.; Hubbard, K.;		
			,	Microwave and Guided Wave Letters, IEEE [see also IEEE Micro	owave and Wireless Components L.	

Volume 8, Issue 5, May 1998 Page(s):194 - 195 Digital Object Identifier 10.1109/75.668708

AbstractPlus | References | Full Text: PDE(72 KB) | IEEE JNL Rights and Permissions 6. Compact W-band solid-state MMIC high power sources Ingram, D.L.; Chen, Y.C.; Stones, I.; Yamauchi, D.; Brunner, B.; Huang, P.; Biedenbender, M.; Ellio DC: lau KF: Yen HC: Microwave Symposium Dinest 2000 IEEE MTT-S International Volume 2. 11-16 June 2000 Pane(s):955 - 958 vol 2 Digital Object Identifier 10 1109/MWSYM 2000 863515 AbstractPlus | Full Text: PDF/276 KR) | IEEE CNF Rights and Permissions 7. A single chip 1-W InP HEMT V-band module Chen. Y.C.; Ingram, D.L.; Yamauchi, D.; Brunner, B.; Kraus, J.; Barsky, M.; Grundbacher, R.; Cha, T.; Wojtowicz, M.; Chin, T.P.; Allen, B.; Yen, H.C.; Streit, D.C.; Gallium Arsenide Integrated Circuit (GaAs IC) Symposium, 1999, 21st Annual 17-20 Oct. 1999 Page(s):149 - 152 Digital Object Identifier 10.1109/GAAS.1999.803747 AbstractPlus | Full Text: PDF(344 KB) IEEE CNF Rights and Permissions 8. Composite-channel InP HEMT for W-band power amplifiers Chen, Y.C.; Chin, P.; Ingram, D.; Lai, R.; Grundbacher, R.; Barsky, M.; Block, T.; Woltowicz, M.; Tra Yen, H.C.; Streit, D.C.; Brown, A.; indium Phosphide and Related Materials. 1999. IPRM. 1999 Eleventh International Conference on 16-20 May 1999 Page(s):305 - 306 Digital Object Identifier 10.1109/ICIPRM.1999.773695 AbstractPlus | Full Text: PDF(120 KB) IEEE CNF Rights and Permissions 9. A highly integrated multi-functional chip set for low cost Ka-band transceiver Ingram, D.L.; Sjogren, L.; Kraus, J.; Nishimoto, M.; Siddiqui, M.; Sing, S.; Cha, K.; Huang, M.; Lai, R. Microwave Symposium Digest, 1998 IEEE MTT-S International Volume 1, 7-12 June 1998 Page(s):301 - 304 vol.1 Digital Object Identifier 10 1109/MWSYM 1998 689379 AbstractPlus | Full Text: PDF(436 KB) IEEE CNF Rights and Permissions 10. A highly integrated multi-functional chip set for low cost Ka-band transceiver

10. A highly integrated multi-functional chip set for low cost Ka-band transceiver Ingram, D.L. Spojen, L.; Kraus, J.; Nehmido, M.; Siddiqui, M.; Sing, S.; Che, K.; Huang, M.; Lai, R. Bridds Frequency. Integrated, Circuits (RFIC) Symposium. 1998 IEEE 7-3 June 1998 Page(1):27 - 230 Digital Coject identifier 10.1109/RFIC: 1998 852096 Abstracticus | Full Text: EDE(432 KB) | IEEE CNF Rights and Permissions 11. A 6 watt Ka-band MMIC power module using MMIC power amplifiers Ingram, D.L.; Stones, D.I.; Huang, T.W.; Nishinoto, M.; Wang, H.; Siddiqui, M.; Tamura, D.; Elliott, Biedenbender, M.; Yen, H.C.; Allen, B.; Microwers Symposium Desa: 1997. IEEE MTT-S. International Volume 3, 8-13. June 1997 Page(6):1183 - 1186 vol.3 Digital Coject identifier 10. 1109/MSYM, 1997: 596508 Abstracticus | Full Text: EDE(478 KB) | IEEE CNF

12. Q-band high Isolation GaAs HEMT switches
Ingram, D.L.; Cha, K.; Hubbard, K.; Lai, R.;
Gaillum.farsenide Intersted Clinical (GaAs IC) Symposium. 1996. Technical Digest. 1996. 18th Apn
3-8 Nov. 1996 Page(1929) 292

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